

Features

• 85V/90A,

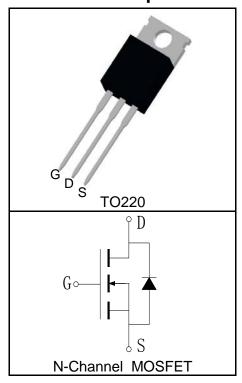
 $R_{DS (ON)} = 5.8 \text{m}\Omega(\text{Typ.}) @V_{GS} = 10 \text{V}$

- Ultra Low On-Resistance
- Fast Switching and Fully Avalanche Rated
- 100% avalanche tested
- 175°C Operating Temperature
- Lead Free and Green Devices Available (RoHS Compliant)

Applications

- High Speed Power Switching
- UPS

Pin Description



Absolute Maximum Ratings

| Symbol | Parameter | Rating | Unit | | | | | | |
|--|--|----------------------|------------|------|--|--|--|--|--|
| Common Ratings (T _c =25°C Unless Otherwise Noted) | | | | | | | | | |
| V _{DSS} | Drain-Source Voltage | | 85 | V | | | | | |
| V _{GSS} | Gate-Source Voltage | | ±25 | V | | | | | |
| T _J | Maximum Junction Temperature | | 175 | °C | | | | | |
| T _{STG} | Storage Temperature Range | | -55 to 175 | °C | | | | | |
| I _S | Diode Continuous Forward Current | 90 | Α | | | | | | |
| Mounted on | Mounted on Large Heat Sink | | | | | | | | |
| I _{DP} (1) | 300µs Pulse Drain Current Tested | T _C =25°C | 360 | Α | | | | | |
| <u> </u> | Continuous Prain Current(// _10)/) | 90 | ۸ | | | | | | |
| $I_D^{\textcircled{2}}$ | Continuous Drain Current(V _{GS} =10V) | 64 | Α | | | | | | |
| P _D | Maying up Daylar Dissipation | 188 | 107 | | | | | | |
| | Maximum Power Dissipation | 94 | W | | | | | | |
| $R_{	heta JC}$ | Thermal Resistance-Junction to Case | • | 0.8 | °C/W | | | | | |
| $R_{	hetaJA}$ | Thermal Resistance-Junction to Ambient | 62.5 | °C/W | | | | | | |
| Drain-Source Avalanche Ratings | | | | | | | | | |
| E _{AS} | Avalanche Energy, Single Pulsed | 306 | mJ | | | | | | |



Electrical Characteristics (T_C=25°C Unless Otherwise Noted)

| 0 | Donomoston | Took Condition | | 11 | | |
|---------------------|----------------------------------|---|------|------|------|------|
| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Unit |
| Static Cha | racteristics | | | | • | |
| BV _{DSS} | Drain-Source Breakdown Voltage | V _{GS} =0V, I _{DS} =250μA | 85 | 90 | | V |
| 1 | Zoro Cata Valtaga Drain Current | V _{DS} =85V, V _{GS} =0V | | | 1 | μA |
| I _{DSS} | Zero Gate Voltage Drain Current | T _J =125°C | | | 30 | |
| $V_{GS(th)}$ | Gate Threshold Voltage | V _{DS} =V _{GS} , I _{DS} =250μA | 2 | 3 | 4 | V |
| I _{GSS} | Gate Leakage Current | V_{GS} =±25V, V_{DS} =0V | | | ±100 | nA |
| R _{DS(ON)} | Drain-Source On-state Resistance | V _{GS} =10V, I _{DS} =45A | | 5.8 | 8 | mΩ |
| | racteristics | | | | | |
| V _{SD} | Diode Forward Voltage | I _{SD} =45A, V _{GS} =0V | | | 1.2 | V |
| trr | Reverse Recovery Time | L 450 dl/dk 4000/vo | | 29 | | ns |
| Qrr | Reverse Recovery Charge | Isb=45A, dlsb/dt=100A/µs | | 45 | | nC |
| Dynamic C | Characteristics (5) | | | - | | |
| R_{G} | Gate Resistance | V _{GS} =0V,V _{DS} =0V,F=1MHz | | 1.3 | | Ω |
| C _{iss} | Input Capacitance | V _{GS} =0V, | | 4350 | | |
| C _{oss} | Output Capacitance | V _{DS} =40V, Frequency=1.0MHz | | 480 | | pF |
| C _{rss} | Reverse Transfer Capacitance | Trequency=1.0MHz | | 275 | | |
| t _{d(ON)} | Turn-on Delay Time | | | 25 | | |
| t _r | Turn-on Rise Time | V _{DD} =40V,I _{DS} =45A, | | 49 | | ns |
| $t_{d(OFF)}$ | Turn-off Delay Time | V_{GEN} =10V, R_{G} =0.8 Ω | | 121 | | |
| t _f | Turn-off Fall Time | | | 17 | | |
| Gate Char | ge Characteristics ^⑤ | | | • | | |
| Q _g | Total Gate Charge | | | 48 | | |
| Q _{gs} | Gate-Source Charge | V _{DS} =68V, V _{GS} =10V, I _{DS} =45A | | 13 | | nC |
| Q_{gd} | Gate-Drain Charge | 108-101 | | 16 | | |

Notes:

- ①Pulse width limited by safe operating area.
- ②Calculated continuous current based on maximum allowable junction temperature. The package limitation current is 75A.
- $\ \ \, \mbox{3Limited by T}_{\mbox{Jmax}}, \mbox{ I}_{\mbox{AS}} = 35\mbox{A}, \mbox{ V}_{\mbox{DD}} = 48\mbox{V}, \mbox{ R}_{\mbox{G}} = 50\Omega$, Starting T $_{\mbox{J}} = 25\mbox{°C}.$
- ④Pulse test;Pulse width≤300µs, duty cycle≤2%.
- ⑤Guaranteed by design, not subject to production testing.

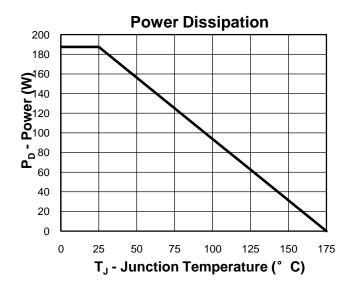


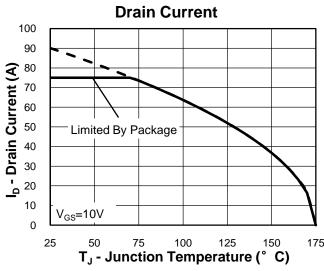
Ordering and Marking Information

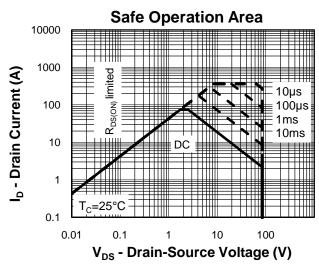
| Device | Marking | Package | Packaging | Quantity | Reel Size | Tape width |
|---------|---------|---------|-----------|----------|-----------|------------|
| RU8590R | RU8590R | TO220 | Tube | 50 | - | = |

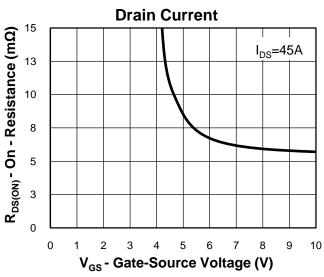


Typical Characteristics

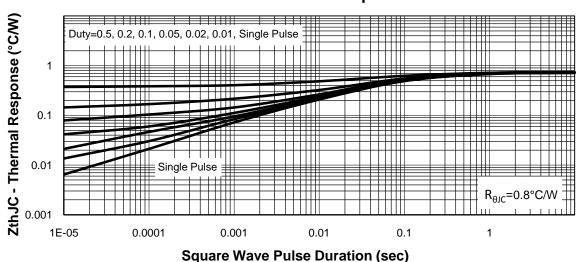






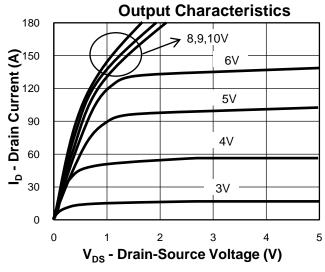


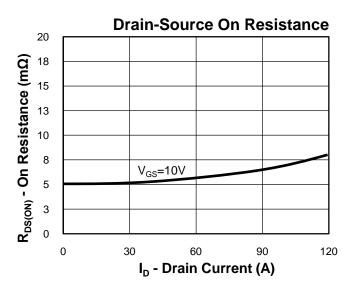
Thermal Transient Impedance

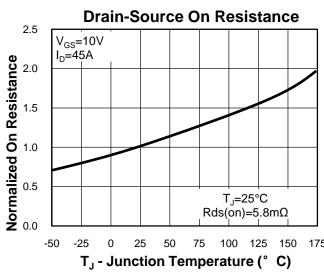


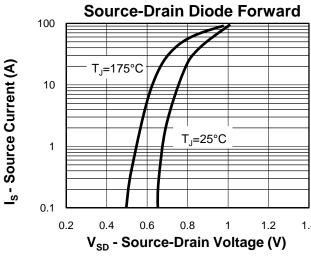


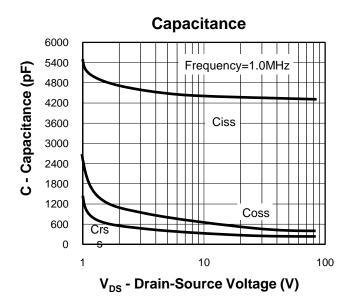
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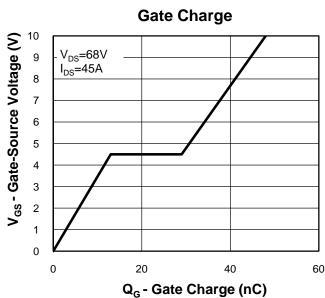






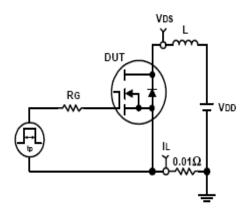


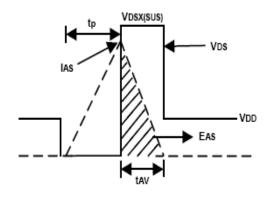




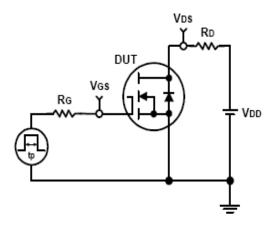


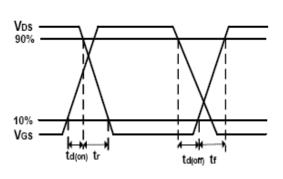
Avalanche Test Circuit and Waveforms





Switching Time Test Circuit and Waveforms

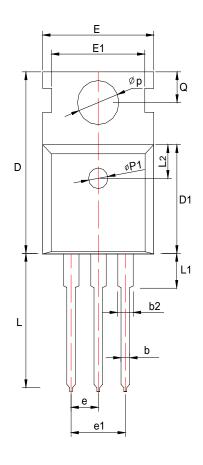


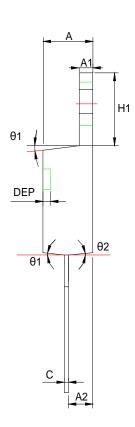


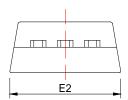


Package Information

TO220







| SYMBOL | MM | | INCH | | SYMBOL | MM | | INCH | | | | | |
|--------|-------|-------|-------|-------|--------|-------|--------|-------|----------|-------|-------|-----------|-------|
| OIMDOL | MIN | NOM | MAX | MIN | NOM | MAX | OIMDOL | MIN | NOM | MAX | MIN | NOM | MAX |
| A | 4.40 | 4.55 | 4.70 | 0.173 | 0.179 | 0.185 | Фр1 | 1.40 | 1.50 | 1.60 | 0.055 | 0.059 | 0.063 |
| A1 | 1.20 | 1.30 | 1.40 | 0.047 | 0.051 | 0.055 | е | | 2.54 BSC | - | | 0.10 BSC | |
| A2 | 2.23 | 2.38 | 2.53 | 0.088 | 0.094 | 0.100 | e1 | | 5.08 BSC | | | 0.20 BSC | |
| b | 0.75 | 0.80 | 0.85 | 0.030 | 0.031 | 0.033 | H1 | 6.40 | 6.50 | 6.60 | 0.252 | 0.256 | 0.260 |
| b2 | 1. 17 | 1.28 | 1.39 | 0.046 | 0.050 | 0.055 | L | 12.70 | 13.18 | 13.65 | 0.500 | 0.519 | 0.537 |
| С | 0.40 | 0.50 | 0.60 | 0.016 | 0.020 | 0.024 | L1 | * | * | 3.95 | * | * | 0.156 |
| D | 15.40 | 15.60 | 15.80 | 0.606 | 0.614 | 0.622 | L2 | | 2.50 REF | | | 0.098 REF | 7 |
| D1 | 8.96 | 9.21 | 9.46 | 0.353 | 0.363 | 0.372 | Φр | 3.50 | 3.60 | 3.70 | 0.138 | 0.142 | 0.146 |
| DEP | 0.05 | 0.13 | 0.20 | 0.002 | 0.005 | 0.008 | Q | 2.73 | 2.80 | 2.87 | 0.107 | 0.110 | 0.113 |
| Е | 9.66 | 9.97 | 10.28 | 0.380 | 0.393 | 0.405 | θ1 | 5° | 7° | 9° | 5° | 7° | 9° |
| E1 | * | 8.70 | * | * | 0.343 | * | θ2 | 1° | 3° | 5° | 1° | 3° | 5° |
| E2 | 9.80 | 10.00 | 10.20 | 0.386 | 0.394 | 0.402 | | | | | | | |



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